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# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China











#### **DUAL N-CHANNEL ENHANCEMENT MODE MOSFET**

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C	
60V	$2\Omega$ @ $V_{GS} = 4.5V$	350mA	
60 V	$2.5\Omega$ @ $V_{GS} = 2.5V$	SSUIIA	

### **Description**

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- Motor Control
- Power Management Functions

### **Features**

- Dual N-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

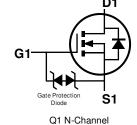
- Case: SOT363
- Case Material: Molded Plastic. "Green" Molding Compound.
  UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish Annealed over Alloy 42 Leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Terminal Connections: See Diagram
- Weight: 0.006 grams (Approximate)

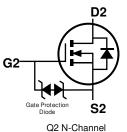


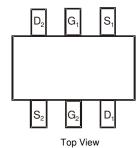


Top View

**SOT363** 







Pin out

Equivalent Circuit

Lquivalent Onc

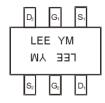
Ordering Information (Note 4)

Part Number	Case	Packaging
DMN62D0UDW-7	SOT363	3000/Tape & Reel
DMN62D0UDW-13	SOT363	10000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information



LEE = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: D = 2016) M = Month (ex: 9 = September)

Date Code Key

2410 0040 11												
Year	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	D	Е	F	G	Н		J	K	L	М	N	0
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## $\hline \textbf{Maximum Ratings} \ (@T_A = +25^{\circ}C, \, \text{unless otherwise specified.})$

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage	$V_{DSS}$	60	V		
Gate-Source Voltage	$V_{GSS}$	±20	V		
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$			I <sub>D</sub>	350 290	mA
Maximum Continuous Body Diode Forward Curren	(Note 6)	Is	0.4	Α	

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		$P_{D}$	320	mW
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	400	°C/W
Total Power Dissipation (Note 6)		$P_{D}$	410	mW
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	312	°C/W
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +150	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

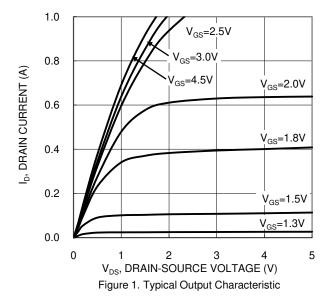
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	$BV_{DSS}$	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_		1.0	μΑ	$V_{DS} = 60V$ , $V_{GS} = 0V$
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±10	μΑ	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(TH)}$	0.5	_	1.0	V	$V_{DS} = 10V, I_D = 250\mu A$
			1.2	2.0		$V_{GS} = 4.5V, I_D = 0.1A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		1.4	2.5	Ω	$V_{GS} = 2.5V, I_D = 0.05A$
			1.8	3.0		$V_{GS} = 1.8V, I_D = 0.05A$
Forward Transconductance	Y <sub>fs</sub>	_	1.8	_	S	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	V <sub>SD</sub>	_	8.0	1.3	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	32	_	рF	V 00V V 0V
Output Capacitance	Coss	_	3.9	-	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	2.4	_	рF	1 = 1.0WI 12
Gate Resistance	$R_g$	_	101	_	Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	Qg	_	0.5	_	nC	V 45V V 40V
Gate-Source Charge	Q <sub>gs</sub>	_	0.09	_	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	$Q_{gd}$	_	0.09	_	nC	I <sub>D</sub> = 250mA
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.4	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	2.5	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	22.6	_	ns	$R_G = 25\Omega$ , $I_D = 200mA$
Turn-Off Fall Time	t <sub>F</sub>	_	12.5	_	ns	

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout
 Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.







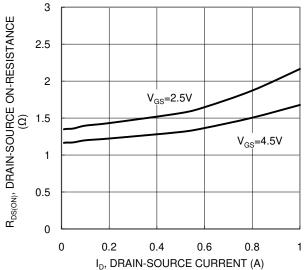


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

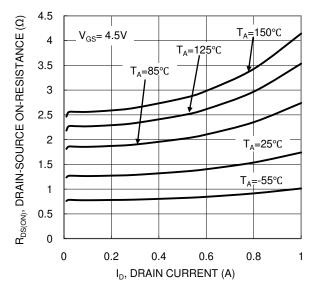
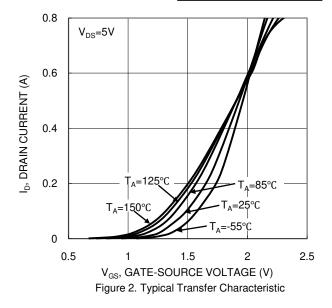
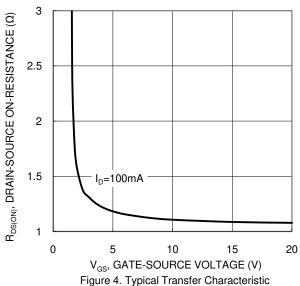


Figure 5. Typical On-Resistance vs. Drain Current and Temperature





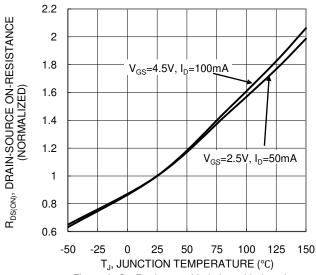


Figure 6. On-Resistance Variation with Junction Temperature





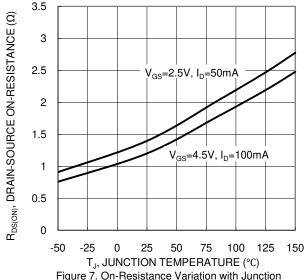
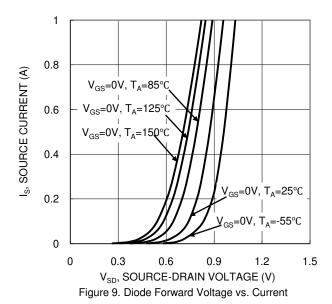
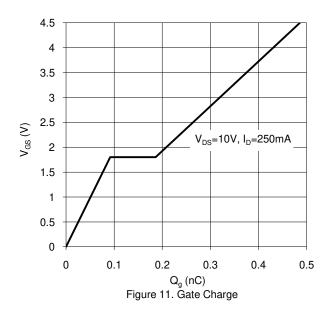
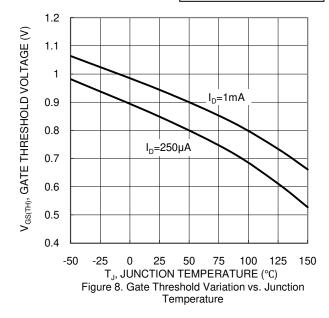
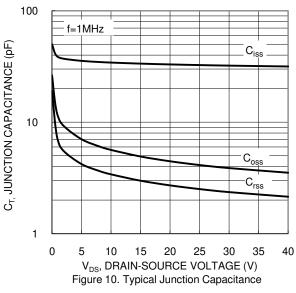


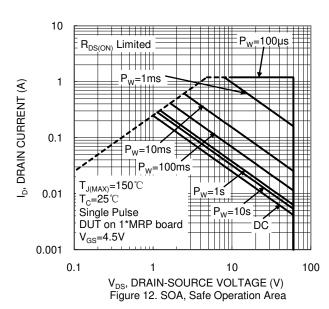
Figure 7. On-Resistance Variation with Junction Temperature



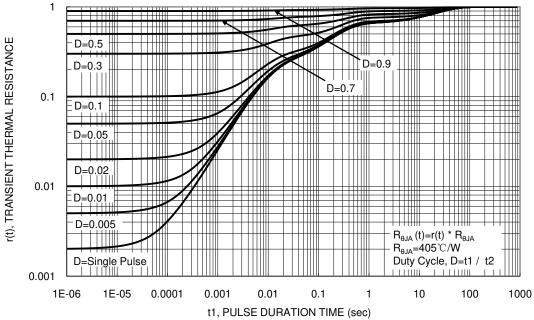










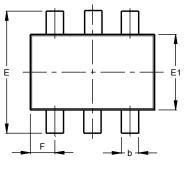


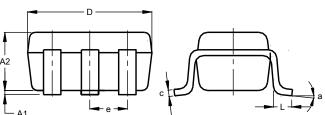


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

### **SOT363**



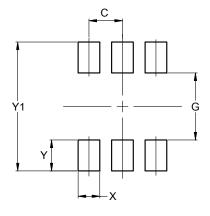


SOT363								
Dim	Min Max Typ							
A1	0.00	0.10	0.05					
A2	0.90	1.00	1.00					
b	0.10	0.30	0.25					
С	0.10	0.22	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
е	0.650 BSC							
F	0.40	0.45	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All Dimensions in mm								

## **Suggested Pad Layout**

 $Please\ see\ http://www.diodes.com/package-outlines.html\ for\ the\ latest\ version.$ 

### **SOT363**



Dimensions	Value (in mm)
С	0.650
G	1.300
X	0.420
Υ	0.600
Y1	2.500



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